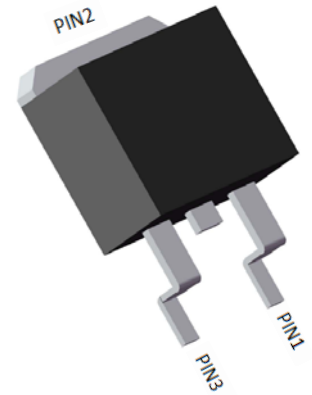
Ultra-Fast Recovery Diodes 10A*2 FRED



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package**: TO-263
  Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity**: As marked

■Maximum Ratings (Tj=25℃ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURB2020CT
Device marking code			MURB2020CT
Repetitive Peak Reverse Voltage	V_{RRM}	V	200
Average Rectified Output Current @60Hz sine wave, R-load, T_C(FIG.1)	I_O	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T_j=25℃	I_{FSM}	A	120
Current Squared Time @1ms≤t≤8.3ms Tj=25℃,	I^2t	A^2s	60
Storage Temperature	Tstg	℃	-55 ~ +175
Junction Temperature	Tj	℃	-55 ~ +175
Typical Junction capacitance @4V,1MHz	Cj	pF	150

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	I_{FM}=10.0A @Tj=25℃		-	0.90	1.0
			I_{FM}=10.0A @Tj=150℃			0.78	0.9
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	uA	V_{RM}=V_{RRM} Tj=25℃		-	-	5.0
	I_{RRM2}		V_{RM}=V_{RRM} Tj=150℃		-	30	50
Reverse Recovery Time	Trr	ns	I_F=0.5A I_{RM}=1A I_{RR}=0.25A Tj=25℃		-	25	35
			Tj=25℃	IF=10A di/dt=-200A/us V_{RM}=100V		34.5	
			Tj=125℃			50.5	
Peak recovery current	I_{RRM}	A	Tj=25℃			5.35	-
			Tj=125℃		-	8.25	-
Reverse recovery charge	Qrr	nC	Tj=25℃		-	90.5	-
			Tj=125℃		-	200.0	-

■Thermal Characteristics （Tj=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	MURB2020CT
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	℃/W	2.0
Thermal Resistance	Between junction and Air	$R_{\theta J-A}$	℃/W	50

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MURB2020CT	Approximate 1.43	50	2000	8000	Tube
MURB2020CT	Approximate 1.43	1000	2000	10000	Reel

■Characteristics (Typical)

FIG1:Io -Tc Curve

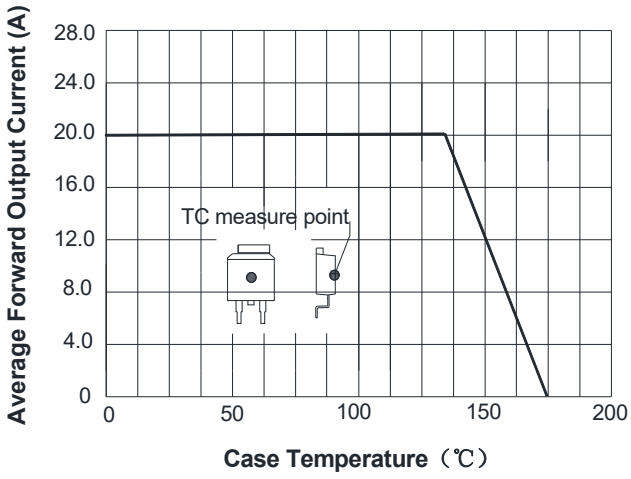


FIG2:Surge Forward Current Capability

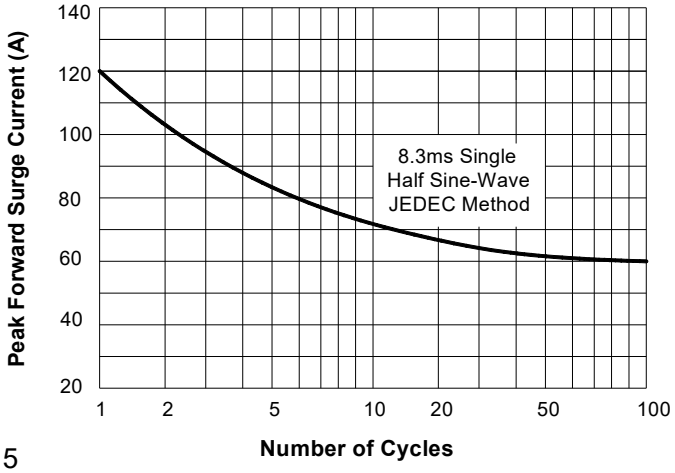


FIG3: Forward Voltage

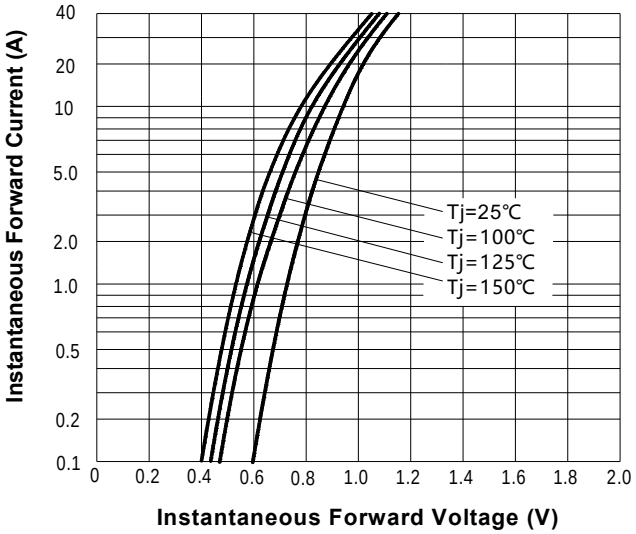


FIG.4: Instantaneous Reverse Characteristics

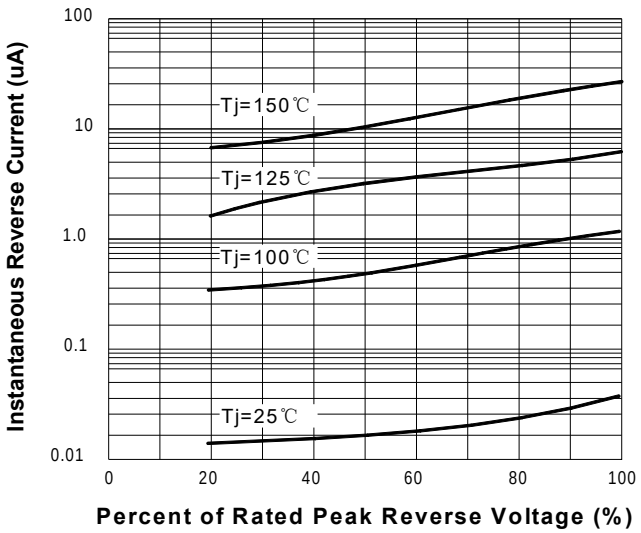
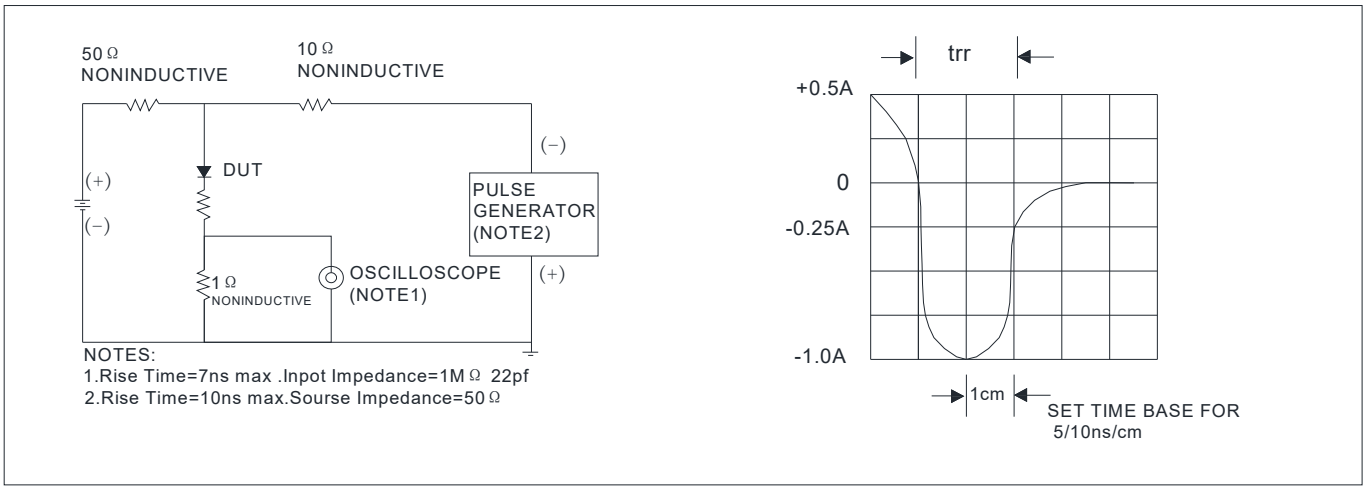
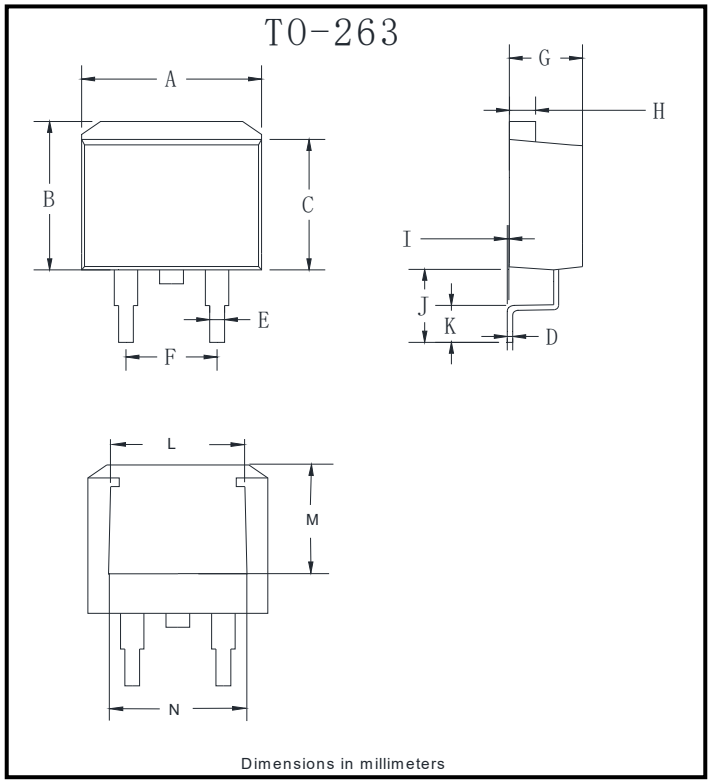


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

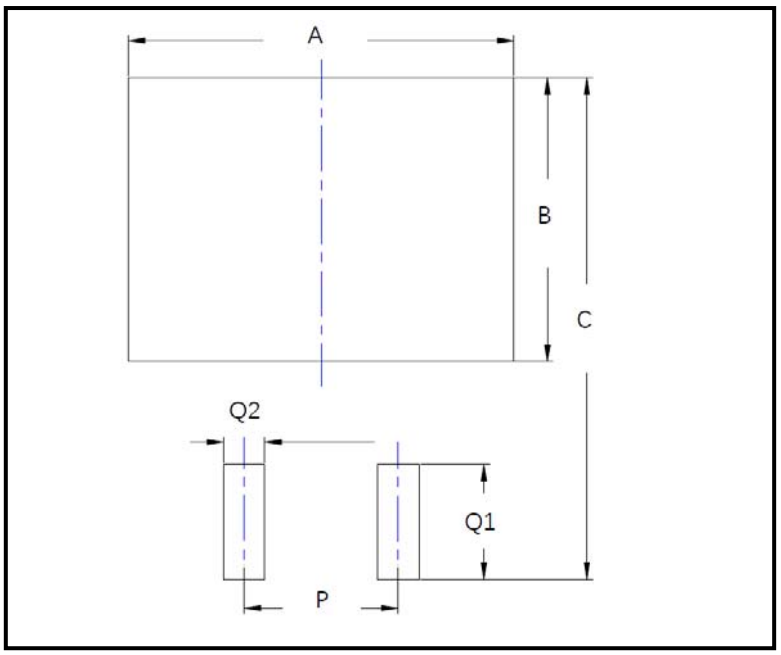


■Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ Suggested Pad Layout



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35

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